## Features

- Exceptional Broadband Performance
- Low Loss:

$$
\begin{aligned}
& \mathrm{T}_{\mathrm{X}}=0.33 \mathrm{~dB} @ 2010 \mathrm{MHz}, 5 \mathrm{~V} / 20 \mathrm{~mA} \\
& \mathrm{~T}_{\mathrm{X}}=0.38 \mathrm{~dB} @ 3.5 \mathrm{GHz}, 5 \mathrm{~V} / 20 \mathrm{~mA}
\end{aligned}
$$

- High Isolation:

$$
\begin{aligned}
& \mathrm{R}_{\mathrm{X}}=44 \mathrm{~dB} @ 2010 \mathrm{MHz}, 20 \mathrm{~mA} / 5 \mathrm{~V} \\
& \mathrm{R}_{\mathrm{X}}=36 \mathrm{~dB} @ 3.5 \mathrm{GHz}, 20 \mathrm{~mA} / 5 \mathrm{~V}
\end{aligned}
$$

- High $\mathrm{T}_{\mathrm{x}}$ RF Input Power:

50 W CW @ 2010 MHz

- High Tx RF Input Peak Power:
>1000 W
- Suitable for Very High Power TD-SCDMA \& WiMAX Applications
- Surface Mount 4 mm PQFN Package
- RoHS* Compliant


## Description and Applications

The MASW-000834-13560T is a SPDT broadband, high linearity, common anode, PIN diode T/R switch, for $0.05-6.0 \mathrm{GHz}$ applications, including WiMAX \& WiFi. The device is provided in industry standard 4 mm PQFN plastic packaging. This device incorporates a PIN diode die fabricated with MACOMs' patented silicon-glass $\mathrm{HMIC}^{\text {TM }}$ process. This chip features two silicon pedestals embedded in a low loss, low dispersion glass. The diodes are formed on the top of each pedestal. The topside is fully encapsulated with silicon nitride and has an additional polymer passivation layer that prevents damage and contamination during handling and assembly.

This compact SPDT switch offers wideband performance with excellent isolation to loss ratio for both $\mathrm{T}_{\mathrm{X}}$ and $\mathrm{R}_{\mathrm{X}}$ states. The PIN diode provides 50 W typical CW power handling and 65 dBm IIP3 at 2010 MHz for maximum switch performance.

## Ordering Information

| Part Number | Package |
| :---: | :---: |
| MASW-000834-13560T | 1000 piece reel |
| MASW-000834-001SMB | Sample Board |
| MADR-008851-0001TB $^{1}$ | Sample Board |

[^0]
## Functional Diagram (Top View)



Pin Configuration ${ }^{2}$

| Pin | Function | Pin | Function |
| :---: | :---: | :---: | :---: |
| 1 | GND | 9 | DC2 |
| 2 | ANT | 10 | N/C |
| 3 | GND | 11 | N/C |
| 4 | N/C | 12 | N/C |
| 5 | N/C | 13 | GND |
| 6 | GND | 14 | $T_{X}$ |
| 7 | RX | 15 | GND |
| 8 | GND | 16 | N/C |

2. The exposed pad centered on the package bottom must be connected to RF, DC and thermal ground.

* Restrictions on Hazardous Substances, European Union Directive 2011/65/EU.


## Electrical Specifications ${ }^{3}$ :

$\mathrm{T}_{\mathrm{A}}=+\mathbf{2 5}{ }^{\circ} \mathrm{C}, 20 \mathrm{~mA} / 5 \mathrm{~V}, \mathrm{P}_{\mathrm{INC}}=0 \mathrm{dBm}, \mathrm{Z}_{0}=50 \Omega$

| Parameter | Symbol | Units | Min. | Typ. | Max. |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{F}=900 \mathrm{MHz}$ |  |  |  |  |  |
| Insertion Loss, $\mathrm{R}_{\mathrm{X}}$ | $\begin{aligned} & \mathrm{R}_{\mathrm{x}} \end{aligned}$ | dB | - | 0.34 | 0.56 |
| Insertion Loss, $\mathrm{T}_{\mathrm{X}}$ | $\begin{aligned} & \mathrm{T}_{\mathrm{X}} \\ & \mathrm{IL} \end{aligned}$ | dB | - | 0.26 | 0.445 |
| Isolation, ANT To R ${ }_{\text {X }}$ | $\begin{gathered} \mathrm{R}_{\mathrm{x}} \\ \text { ISO } \end{gathered}$ | dB | 45.8 | 52.1 | - |
| Isolation, ANT To ${ }_{\text {x }}$ | $\begin{gathered} \mathrm{T}_{\mathrm{X}} \\ \text { ISO } \end{gathered}$ | dB | 21.7 | 27.1 | - |
| $\mathrm{F}=1800 \mathrm{MHz}$ |  |  |  |  |  |
| Insertion Loss, $\mathrm{R}_{\mathrm{X}}$ | $\mathrm{R}_{\mathrm{X}}^{\mathrm{IL}}$ | dB | - | 0.40 | 0.72 |
| Insertion Loss, $\mathrm{T}_{\mathrm{X}}$ | $\begin{aligned} & \text { Tx } \\ & \text { IL } \end{aligned}$ | dB | - | 0.32 | 0.49 |
| Isolation, ANT To $\mathrm{R}_{\mathrm{X}}$ | $\begin{aligned} & \mathrm{Rx} \\ & \text { ISO } \end{aligned}$ | dB | 43.7 | 48.9 | - |
| Isolation, ANT To Tx | $\begin{gathered} \mathrm{T}_{\mathrm{X}} \\ \text { ISO } \end{gathered}$ | dB | 18.4 | 21.4 | - |
| F $=2010 \mathrm{MHz}$ |  |  |  |  |  |
| Insertion Loss, $\mathrm{R}_{\mathrm{X}}$ | $\begin{aligned} & \mathrm{R}_{\mathrm{X}} \\ & \mathrm{IL} \end{aligned}$ | dB | - | 0.42 | 0.75 |
| Insertion Loss, $\mathrm{T}_{\mathrm{X}}$ | $\begin{aligned} & \hline \mathrm{T}_{\mathrm{X}} \\ & \mathrm{IL} \end{aligned}$ | dB | - | 0.33 | 0.5 |
| Isolation, ANT To Rx | $\begin{aligned} & \mathrm{R}_{\mathrm{x}} \\ & \text { ISO } \end{aligned}$ | dB | 43.2 | 44.6 | - |
| Isolation, ANT To Tx | $\begin{gathered} \mathrm{T}_{\mathrm{X}} \\ \text { ISO } \end{gathered}$ | dB | 17.7 | 19.9 | - |
| Input Return Loss, $\mathrm{T}_{\mathrm{x}}$ | $\begin{aligned} & \mathrm{T}_{\mathrm{X}} \\ & \mathrm{RL} \end{aligned}$ | dB | - | 32.1 | - |
| Input Return Loss, $\mathrm{R}_{\mathrm{X}}$ | $\begin{aligned} & \mathrm{R}_{\mathrm{X}} \\ & \mathrm{RL} \end{aligned}$ | dB | - | 24.2 | - |

[^1]
## Electrical Specifications ${ }^{3}$ :

$\mathrm{T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}, 20 \mathrm{~mA} / 5 \mathrm{~V}, \mathrm{P}_{\mathrm{INC}}=0 \mathrm{dBm}, \mathrm{Z}_{0}=50 \Omega$

| Parameter | Symbol | Units | Min. | Typ. | Max. |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{F}=2.3$ - $\mathbf{2 . 7} \mathbf{~ G H z}$ |  |  |  |  |  |
| Insertion Loss, $\mathrm{R}_{\mathrm{X}}$ | $\begin{aligned} & \mathrm{R} \mathrm{R} \\ & \mathrm{IL} \end{aligned}$ | dB | - | 0.46 | 0.84 |
| Insertion Loss, $\mathrm{T}_{\mathrm{X}}$ | $\begin{aligned} & \mathrm{T}_{\mathrm{X}} \\ & \mathrm{IL} \end{aligned}$ | dB | - | 0.35 | 0.525 |
| Isolation, ANT To Rx | $\begin{gathered} \mathrm{R}_{\mathrm{x}} \\ \mathrm{ISO} \end{gathered}$ | dB | 40.2 | 41.2 | - |
| Isolation, ANT To $\mathrm{T}_{\mathrm{x}}$ | $\begin{gathered} \mathrm{T}_{\mathrm{X}} \\ \text { ISO } \end{gathered}$ | dB | 16.2 | 18.6 | - |
| Input Return Loss, $\mathrm{T}_{\mathrm{X}}$ | $\begin{aligned} & \mathrm{T}_{\mathrm{X}} \\ & \mathrm{RL} \end{aligned}$ | dB | - | 30.5 | - |
| Input Return Loss, $\mathrm{R}_{\mathrm{X}}$ | $\begin{aligned} & \mathrm{R}_{\mathrm{X}} \\ & \mathrm{RL} \end{aligned}$ | dB | - | 22.9 | - |
| $\mathrm{F}=3.3-3.8 \mathrm{GHz}$ |  |  |  |  |  |
| Insertion Loss, $\mathrm{R}_{\mathrm{X}}$ | $\mathrm{R}_{\mathrm{X}} \mathrm{L}$ | dB | - | 0.56 | 1.0 |
| Insertion Loss, $\mathrm{T}_{\mathrm{X}}$ | $\mathrm{T}_{\mathrm{I}} \mathrm{L}$ | dB | - | 0.38 | 0.575 |
| Isolation, ANT To R ${ }_{\text {x }}$ | $\begin{gathered} \mathrm{R}_{\mathrm{x}} \\ \mathrm{ISO} \end{gathered}$ | dB | 33.7 | 35.9 | - |
| Isolation, ANT To TX | $\begin{gathered} \mathrm{T}_{\mathrm{X}} \\ \text { ISO } \end{gathered}$ | dB | 13.6 | 16.1 | - |
| Input Return Loss, $\mathrm{T}_{\mathrm{X}}$ | $\begin{aligned} & \mathrm{T}_{\mathrm{X}} \\ & \mathrm{RL} \end{aligned}$ | dB | - | 27.4 | - |
| Input Return Loss, $\mathrm{R}_{\mathrm{x}}$ | $\begin{aligned} & R_{X} \\ & \text { RL } \end{aligned}$ | dB | - | 21.9 | - |
| $\mathrm{F}=4.9-5.9 \mathrm{GHz}$ |  |  |  |  |  |
| Insertion Loss, $\mathrm{R}_{\mathrm{X}}$ | $\begin{aligned} & \mathrm{R}_{\mathrm{X}} \\ & \mathrm{IL} \end{aligned}$ | dB | - | 0.78 | - |
| Insertion Loss, $\mathrm{T}_{\mathrm{X}}$ | ${ }_{\text {IL }}^{\text {IL }}$ | dB | - | 0.52 | - |
| Isolation, ANT To R ${ }_{\mathrm{X}}$ | $\begin{gathered} \mathrm{R}_{\mathrm{X}} \\ \mathrm{ISO} \end{gathered}$ | dB | - | 26.4 | - |
| Isolation, ANT To Tx | $\begin{gathered} \mathrm{T}_{\mathrm{X}} \\ \text { ISO } \end{gathered}$ | dB | - | 11.8 | - |
| Input Return Loss, $\mathrm{T}_{\mathrm{X}}$ | $\begin{aligned} & \mathrm{T}_{\mathrm{X}} \\ & \mathrm{RL} \end{aligned}$ | dB | - | 20.3 | - |
| Input Return Loss, $\mathrm{R}_{\mathrm{X}}$ | $\begin{aligned} & R_{x} \\ & R L \end{aligned}$ | dB | - | 24.2 | - |

## Electrical Specifications ${ }^{4}$ :

$\mathrm{T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}, 50 \mathrm{~mA} / 25 \mathrm{~V}, \mathrm{P}_{\mathrm{INC}}=0 \mathrm{dBm}, \mathrm{Z}_{0}=50 \Omega$

| Parameter | Symbol | Units | Min. | Typ. | Max. |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{F}=900 \mathrm{MHz}$ |  |  |  |  |  |
| Insertion Loss, $\mathrm{R}_{\mathrm{X}}$ | $\begin{aligned} & \mathrm{R}_{\mathrm{x}} \end{aligned}$ | dB | - | 0.27 | - |
| Insertion Loss, $\mathrm{T}_{\mathrm{X}}$ | $\begin{aligned} & \mathrm{T}_{\mathrm{X}} \\ & \mathrm{IL} \end{aligned}$ | dB | - | 0.22 | - |
| Isolation, ANT To Rx | $\begin{gathered} \mathrm{R}_{\mathrm{x}} \\ \text { ISO } \end{gathered}$ | dB | - | 53.3 | - |
| Isolation, ANT To $\mathrm{T}_{\mathrm{X}}$ | $\begin{gathered} \mathrm{T}_{\mathrm{X}} \\ \text { ISO } \end{gathered}$ | dB | - | 27.4 | - |
| $\mathrm{F}=1800 \mathrm{MHz}$ |  |  |  |  |  |
| Insertion Loss, $\mathrm{R}_{\mathrm{X}}$ |  | dB | - | 0.32 | - |
| Insertion Loss, $\mathrm{T}_{\mathrm{X}}$ | $\mathrm{T}_{\mathrm{X}} \mathrm{L}$ | dB | - | 0.27 | - |
| Isolation, ANT To R ${ }_{\text {X }}$ | $\begin{array}{r} \mathrm{R}_{\mathrm{X}} \\ \mathrm{ISO} \end{array}$ | dB | - | 50.2 | - |
| Isolation, ANT To TX | $\begin{gathered} \mathrm{T}_{\mathrm{x}} \\ \text { ISO } \end{gathered}$ | dB | - | 21.6 | - |
| $\mathrm{F}=2010 \mathrm{MHz}$ |  |  |  |  |  |
| Insertion Loss, $\mathrm{R}_{\mathrm{X}}$ | $\mathrm{R}_{\mathrm{x}}$ | dB | - | 0.34 | - |
| Insertion Loss, $\mathrm{T}_{\mathrm{X}}$ | $\begin{aligned} & \hline \mathrm{T}_{\mathrm{X}} \\ & \mathrm{IL} \end{aligned}$ | dB | - | 0.28 | - |
| Isolation, ANT To $\mathrm{R}_{\mathrm{X}}$ | $\begin{gathered} \mathrm{R}_{\mathrm{x}} \\ \text { ISO } \end{gathered}$ | dB | - | 45.5 | - |
| Isolation, ANT To Tx | $\begin{gathered} \mathrm{T}_{\mathrm{X}} \\ \text { ISO } \end{gathered}$ | dB | - | 20.1 | - |
| Input Return Loss, $\mathrm{T}_{\mathrm{x}}$ | $\begin{aligned} & \mathrm{T}_{\mathrm{X}} \\ & \mathrm{RL} \end{aligned}$ | dB | - | 33.1 | - |
| Input Return Loss, $\mathrm{R}_{\mathrm{X}}$ | $\begin{aligned} & \mathrm{R}_{\mathrm{X}} \\ & \mathrm{RL} \end{aligned}$ | dB | - | 24.1 | - |

[^2]
## Electrical Specifications ${ }^{4}$ :

$\mathrm{T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}, 50 \mathrm{~mA} / 25 \mathrm{~V}, \mathrm{P}_{\mathrm{INC}}=0 \mathrm{dBm}, \mathrm{Z}_{0}=50 \Omega$

| Parameter | Symbol | Units | Min. | Typ. | Max. |
| :---: | :---: | :---: | :---: | :---: | :---: |
| F = 2.3-2.7 GHz |  |  |  |  |  |
| Insertion Loss, $\mathrm{R}_{\mathrm{X}}$ | $\begin{aligned} & \mathrm{R}_{\mathrm{X}} \\ & \mathrm{IL} \end{aligned}$ | dB | - | 0.38 | - |
| Insertion Loss, $\mathrm{T}_{\mathrm{X}}$ | T I IL | dB | - | 0.30 | - |
| Isolation, ANT To RX | $\begin{gathered} \mathrm{R}_{\mathrm{x}} \\ \text { ISO } \end{gathered}$ | dB | - | 41.8 | - |
| Isolation, ANT To $\mathrm{T}_{\mathrm{x}}$ | $\begin{gathered} \mathrm{T}_{\mathrm{X}} \\ \text { ISO } \end{gathered}$ | dB | - | 18.7 | - |
| Input Return Loss, $\mathrm{T}_{\mathrm{X}}$ | $\begin{aligned} & \mathrm{T}_{\mathrm{X}} \\ & \mathrm{RL} \end{aligned}$ | dB | - | 31.3 | - |
| Input Return Loss, $\mathrm{R}_{\mathrm{X}}$ | $\begin{aligned} & R_{x} \\ & R L \end{aligned}$ | dB | - | 22.8 | - |
| F = 3.3-3.8 GHz |  |  |  |  |  |
| Insertion Loss, $\mathrm{R}_{\mathrm{X}}$ | $\begin{aligned} & \mathrm{RX}_{\mathrm{X}} \\ & \text { IL } \end{aligned}$ | dB | - | 0.47 | - |
| Insertion Loss, $\mathrm{T}_{\mathrm{X}}$ | $\begin{aligned} & \mathrm{T}_{\mathrm{x}} \\ & \mathrm{IL} \end{aligned}$ | dB | - | 0.33 | - |
| Isolation, ANT To RX | $\begin{gathered} \mathrm{R}_{\mathrm{x}} \\ \text { ISO } \end{gathered}$ | dB | - | 36.2 | - |
| Isolation, ANT To $\mathrm{T}_{\mathrm{x}}$ | $\begin{gathered} \mathrm{T}_{\mathrm{X}} \\ \text { ISO } \end{gathered}$ | dB | - | 16.2 | - |
| Input Return Loss, $\mathrm{T}_{\mathrm{X}}$ | $\begin{aligned} & \mathrm{T}_{\mathrm{X}} \\ & \mathrm{RL} \end{aligned}$ | dB | - | 28.0 | - |
| Input Return Loss, Rx | $\begin{aligned} & R_{X} \\ & \mathrm{RL} \end{aligned}$ | dB | - | 21.8 | - |
| $\mathrm{F}=4.9$ - 5.9 GHz |  |  |  |  |  |
| Insertion Loss, $\mathrm{R}_{\mathrm{X}}$ | $\stackrel{\mathrm{R}_{\mathrm{X}}}{\mathrm{IL}}$ | dB | - | 0.72 | - |
| Insertion Loss, $\mathrm{T}_{\mathrm{X}}$ | $\mathrm{T}_{\mathrm{x}}$ | dB | - | 0.48 | - |
| Isolation, ANT To $\mathrm{R}_{\mathrm{X}}$ | $\begin{gathered} \mathrm{R}_{\mathrm{X}} \\ \mathrm{ISO} \end{gathered}$ | dB | - | 26.6 | - |
| Isolation, ANT To TX | $\begin{gathered} \mathrm{T}_{\mathrm{x}} \\ \text { ISO } \end{gathered}$ | dB | - | 11.8 | - |
| Input Return Loss, $\mathrm{T}_{\mathrm{X}}$ | $\begin{aligned} & \mathrm{T}_{\mathrm{X}} \\ & \mathrm{RL} \end{aligned}$ | dB | - | 20.5 | - |
| Input Return Loss, Rx | $\begin{aligned} & R_{X} \\ & R L \end{aligned}$ | dB | - | 24.2 | - |

## Electrical Specifications:

$\mathrm{T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}, 50 \mathrm{~mA} / 25 \mathrm{~V}, \mathrm{Z}_{0}=50 \Omega$

| Parameter | Symbol | Test Conditions | Units | Min. | Typ. | Max. |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Tx Input P1dB | $\begin{gathered} \mathrm{T}_{\mathrm{X}} \\ \mathrm{P} 1 \mathrm{~dB} \end{gathered}$ | 2010 MHz, Tx to Antenna 3.5 GHz, $\mathrm{T}_{\mathrm{X}}$ to Antenna | dBm | - | $\begin{aligned} & >45.5 \\ & >45.0 \end{aligned}$ | - |
| TX $2^{\text {nd }}$ Harmonic | $\begin{gathered} \mathrm{T}_{\mathrm{x}} \\ 2 \mathrm{Fo} \end{gathered}$ | $2010 \mathrm{MHz}, \mathrm{P}_{\mathrm{IN}}=+30 \mathrm{dBm}$ $3.5 \mathrm{GHz}, \mathrm{P}_{\mathrm{IN}}=+30 \mathrm{dBm}$ | dBc | - | $\begin{aligned} & 80 \\ & 88 \end{aligned}$ | - |
| Tx $3^{\text {rd }}$ Harmonic | $\begin{gathered} \mathrm{T}_{\mathrm{X}} \\ 3 \mathrm{Fo} \end{gathered}$ | $\begin{aligned} & 2010 \mathrm{MHz}, \mathrm{P}_{\mathrm{IN}}=+30 \mathrm{dBm} \\ & 3.5 \mathrm{GHz}, \mathrm{P}_{\mathrm{IN}}=+30 \mathrm{dBm} \end{aligned}$ | dBc | - | $\begin{gathered} 95 \\ 105 \end{gathered}$ | - |
| $\mathrm{T}_{\mathrm{x}}$ Input IP3 | $\begin{gathered} \mathrm{T}_{\mathrm{X}} \\ \mathrm{IIP} 3 \end{gathered}$ | $\begin{aligned} & \mathrm{P}_{\mathrm{IN}}=+10 \mathrm{dBm}, \mathrm{~F} 1=2010 \mathrm{MHz}, \mathrm{~F} 2=2020 \mathrm{MHz} \\ & \mathrm{P}_{\mathrm{IN}}=+10 \mathrm{dBm}, \mathrm{~F} 1=3.50 \mathrm{GHz}, \mathrm{~F} 2=3.51 \mathrm{GHz} \end{aligned}$ | dBm | - | $\begin{aligned} & >64 \\ & >64 \end{aligned}$ | - |
| Tx CW Input Power | $\begin{gathered} \mathrm{T}_{\mathrm{X}} \\ \mathrm{P}_{\mathrm{INC}} \\ \hline \end{gathered}$ | $\mathrm{F}=2010 \mathrm{MHz}$ | dBm / W | - | 47 / 50 | - |
| $\mathrm{R}_{\mathrm{x}} \mathrm{CW}$ Input Power | $\begin{gathered} \mathrm{R}_{\mathrm{X}} \\ \mathrm{P}_{\mathrm{INC}} \end{gathered}$ | $\begin{gathered} \mathrm{F}=2010 \mathrm{MHz} \\ \mathrm{~F}=3.5 \mathrm{GHz} \end{gathered}$ | dBm / W | - | $\begin{aligned} & 41.5 / 14 \\ & 40.5 / 11 \end{aligned}$ | - |
| Tx RF Switching Speed | $t_{\text {RF }}$ | $\begin{gathered} \mathrm{F}=2010 \mathrm{MHz}(10-90 \% \mathrm{RF} \text { Voltage }) \\ \mathrm{F}=3.5 \mathrm{GHz}(10-90 \% \mathrm{RF} \text { Voltage }) \\ 1 \mathrm{MHz} \text { Rep Rate in Modulating Mode } \end{gathered}$ | ns | - | $\begin{aligned} & 200 \\ & 200 \end{aligned}$ | - |

## Absolute Maximum Ratings ${ }^{5,6}$

@ $T_{A}=+25^{\circ} \mathrm{C}$ (unless otherwise specified)

| Parameter | Absolute Maximum |
| :---: | :---: |
| Forward Current | $\|100 \mathrm{~mA}\|$ |
| RF \& DC Reverse Voltage | $\|-200 \mathrm{~V}\|$ |
| $\mathrm{T}_{\mathrm{X}}$ Incident CW Power | $50 \mathrm{~W}(47 \mathrm{dBm})^{7}$ <br> $@ 2010 \mathrm{MHz}$ |
| $\mathrm{T}_{\mathrm{X}}$ Peak Incident Power | $>300 \mathrm{~W}, 5 \mu \mathrm{~s}, 1 \%$ duty |
| Junction Temperature | $+175^{\circ} \mathrm{C}$ |
| Operating Temperature | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ |
| Storage Temperature | $-55^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$ |

5. Exceeding these limits may cause permanent damage.
6. MACOM does not recommend sustained operation near these survivability limits.
7. Baseplate Temperature must be controlled to a constant $+25^{\circ} \mathrm{C}$. See derating curve.

## Static Sensitivity

These devices are rated Class 1B Human Body. Proper ESD control techniques should be used when handling these devices.

## Typical Power Derating Curve

$T_{X}$ Maximum CW Input Power
( 50 mA Forward Bias, 2010 MHz)


Note that this part must be held to a constant baseplate temperature to achieve the power handling results specified above. Adding a heatsink to the baseplate will improve performance to values greater than shown here. The increase in maximum input power from using a heatsink depends on the specific heatsink design.

With a sample board mounted onto a heatsink of dimensions and fins shown below, this switch can handle up to 35 W CW of incident power.


## $\mathrm{T}_{\mathrm{X}}$ Performance Curves @+25${ }^{\circ} \mathrm{C}, \mathrm{Z}_{\mathbf{0}}=50 \Omega$

$T_{X}$ Insertion Loss, $20 \mathrm{~mA} \& 50 \mathrm{~mA}$

$T_{X}$ Isolation, 5 V \& 25 V

$\mathrm{R}_{\mathrm{X}}$ Performance Curves $@+25^{\circ} \mathrm{C}, \mathrm{Z}_{0}=50 \Omega$

$R_{X}$ Isolation, 5 V \& 25 V


## Bias Diagrams \& Tables ${ }^{8}$

$\mathrm{T}_{\mathrm{x}}$-ANT Insertion Loss, $\mathrm{R}_{\mathrm{x}}$-ANT Isolation
(Pin 16)

$\mathrm{R}_{\mathrm{x}}$-ANT Insertion Loss, $\mathrm{T}_{\mathrm{x}}$-ANT Isolation
(Pin 16) N/C GND $\mathrm{T}_{\mathrm{x}} \quad$ GND
(Pin 1)


## Bias Table 1

| Parameter | $\mathbf{T}_{\mathbf{x}}$ | $\mathbf{R}_{\mathbf{x}}$ | DC2 | ANT |
| :---: | :---: | :---: | :---: | :---: |
|  | Pin 14 | Pin 7 | Pin 9 | Pin 2 |
| $\mathrm{T}_{\mathrm{x}}$-ANT Insertion Loss | -20 mA | $+5 \mathrm{~V},+20 \mathrm{~mA}$ | -20 mA | $0 \mathrm{~V},+20 \mathrm{~mA}$ |
| $\mathrm{R}_{\mathrm{x}}-\mathrm{ANT}$ Isolation |  |  |  |  |
| $\mathrm{R}_{\mathrm{x}}-\mathrm{ANT}$ Insertion Loss | $+5 \mathrm{~V}, 0 \mathrm{~mA}$ | -20 mA | $+5 \mathrm{~V}, 0 \mathrm{~mA}$ | $0 \mathrm{~V},+20 \mathrm{~mA}$ |
| $\mathrm{~T}_{\mathrm{x}}-\mathrm{ANT}$ Isolation |  |  |  |  |

## Bias Table 2

| Parameter | $\mathbf{T}_{\mathbf{x}}$ | $\mathbf{R}_{\mathbf{x}}$ | DC2 | ANT |
| :---: | :---: | :---: | :---: | :---: |
|  | Pin 14 | Pin 7 | Pin 9 | Pin 2 |
| $\mathrm{T}_{\mathrm{x}}$-ANT Insertion Loss | -50 mA | $+25 \mathrm{~V},+50 \mathrm{~mA}$ | -50 mA | $0 \mathrm{~V},+50 \mathrm{~mA}$ |
| $\mathrm{R}_{\mathrm{x}}-$ ANT Isolation |  |  |  |  |
| $\mathrm{R}_{\mathrm{x}}-\mathrm{ANT}$ Insertion Loss | $+25 \mathrm{~V}, 0 \mathrm{~mA}$ | -50 mA | $+25 \mathrm{~V}, 0 \mathrm{~mA}$ | $0 \mathrm{~V},+50 \mathrm{~mA}$ |
| $\mathrm{~T}_{\mathrm{x}}-\mathrm{ANT}$ Isolation |  |  |  |  |

8. Diode Based Products require different minimum reverse bias voltages depending on the frequency and incident power levels. More details can be found on page 10 of this datasheet.

## Minimum Required Reverse Bias Voltage

Minimum reverse bias voltage on a PIN diode based product varies with frequency of operation and incident power levels. As a rule of thumb, a designer can always use the magnitude of the peak RF voltage or empirically locate lower bias values than the peak RF voltage magnitude. However, it has been shown that lower DC voltages can be used depending on the RF environment in which a diode is placed. In the plot below, the minimum required reverse voltage vs. frequency is shown for an incident RF power of 50 Watts. This trend line will shift lower if the incident RF power is decreased. The biasing values have not been verified through measurement at MACOM. As a result, please use the data below as a guide only for biasing requirements as this data is based solely on generic PIN diode equations. ${ }^{9}$

Please be cautious in that lower reverse bias levels can degrade isolation and distortion in a PIN diode based product.
9. R. Caverly and G. Hiller, "Establishing the Minimum Reverse Bias for a P-I-N Diode in a High Power Switch," IEEE Transactions on Microwave Theory and Techniques, Vol.38, No.12, December 1990.

Reverse Bias Required vs. Frequency (50 W Power Handling)


MASW-000834 and Recommended Driver with +5 V \& +28 V DC Power ${ }^{10,11,12,13,14,15,16,17}$
MADR-008851 is the recommended driver for the MASW-000834 Switch.

10. Forward Bias Diode Voltage: $\mathrm{DV}_{\mathrm{F}}$ is $\sim 0.9 \mathrm{~V} @ 22 \mathrm{~mA} ; \mathrm{DV}_{\mathrm{F}}$ is $\sim 1.0 \mathrm{~V} @ 35 \mathrm{~mA}$
11. R 1 is calculated by $\left(\mathrm{V}_{\mathrm{CC}}-1.5 \mathrm{~V}\right) / I_{\text {SERIES }}$, where $\mathrm{I}_{\text {SERIES }}$ is the desired bias current for the series diodes:

For 21 mA load current, $\mathrm{R} 1=165 \Omega @ \mathrm{~V}_{\mathrm{CC}}=5.0 \mathrm{~V}$ and $82 \Omega @ \mathrm{~V}_{\mathrm{CC}}=3.3 \mathrm{~V}$.
For 32 mA load current, $\mathrm{R} 1=110 \Omega @ \mathrm{~V}_{\mathrm{cc}}=5.0 \mathrm{~V}$ and $56 \Omega @ \mathrm{~V}_{\mathrm{CC}}=3.3 \mathrm{~V}$.
12. $R 2$ is calculated by $\left(\mathrm{V}_{\text {DD }}-1.0 \mathrm{~V}\right) / I_{\text {SHUNT }}$, where $\mathrm{I}_{\text {Shunt }}$ is the desired forward bias current for the shunt diode. The power dissipation is calculated by $\mathrm{I}_{\text {SHUNT }} \times 27 \mathrm{~V}$. For 20 mA of $\mathrm{I}_{\text {SHUNT }}, \mathrm{R} 2$ should use a $2511,1 \mathrm{~W}, 1.3 \mathrm{k} \Omega$ resistor.
13. C8 is already built-in for MASW-000834-13560T switch.
14. The voltage at the common anode will be approximately 1.5 V .
15. The current in through the back-biased diodes will be the leakage current for the diodes.
16. C1-C5, L1-L4, R1, R2, and the switch are discrete components that should be installed on the users board. It is recommended that Coilcraft 0603CS-27NXJLW or equivalent be used for L1-L4 at 2 GHz (values may vary based on the frequency).
17. There are 33 pF bypass capacitors included in the driver for the $\mathrm{R}_{\mathrm{x}}, \mathrm{T}_{\mathrm{X}}$, and SH 1 ports. There are cases (especially at higher frequencies), where the optional 12 pF bypass capacitors ( C 6 and C 7 ) that are shown on the schematic are needed.

## Outline: 4 mm PQFN 16-Lead Saw Singulated



NOTES:

1. REFERENCE JEDEC MO-220. VAR. VGGC FOR ADDITIONAL DMENSIONAL AND TOLERANCE INFORMATION
2. REFERENCE SZOB3 APPLICATION NOTE FOR PCB FOOTPRINT INFORMATION.

3 ALL DMENSIONS SHOWN AS INCHES/MM

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MASW-000834-001SMB MASW-000834-13560T


[^0]:    1. Sample board with recommended external driver \& MASW-000834-13560T switch.
[^1]:    3. See Bias Table 1.
[^2]:    4. See Bias Table 2.
[^3]:    ${ }^{\dagger}$ Reference Application Note S2083 for lead-free solder reflow recommendations.
    Meets JEDEC moisture sensitivity level 1 requirements.

